



### N-CHANNEL ENHANCEMENT MODE MOSFET

Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) Qualified to AEC-Q101 Standards for High Reliability

Case Material: Molded Plastic, "Green" Molding Compound.

UL Flammability Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020 Terminal Connections: See Diagram Below

Weight: 0.072 grams (approximate)

Features and Benefits
Low On-Resistance
Low Input Capacitance
Fast Switching Speed

Mechanical Data

Case: SO-8

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	l <sub>D</sub> max T <sub>A</sub> = +25°C		
	14mΩ @ V <sub>GS</sub> = 10V	10A		
30V	20mΩ @ V <sub>GS</sub> = 4.5V	8A		

## **Description and Applications**

SO-8

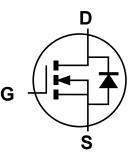
Top View

This MOSFET has been designed to minimize the on-state resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

## 





Equivalent circuit

### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN4468LSS-13	SO-8	2500 / Tape & Reel

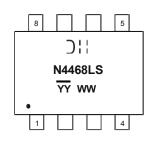
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

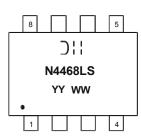
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



Chengdu A/T Site



Shanghai A/T Site

);; = Manufacturer's Marking
N4468LS = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 13 = 2013)
WW = Week (01 - 53)
YY = Date Code Marking for SAT (Shanghai Assembly/ Test site)
YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteri	stic		Symbol	Value	Unit
Drain-Source Voltage			Vdss	30	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 5)	Steady State	TA = +25°C TA = +70°C	lD	10 9	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			ldм	50	A

## **Thermal Characteristics**

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	1.52	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta}$ JA	82	°C/W
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta Jc}$	8.2	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

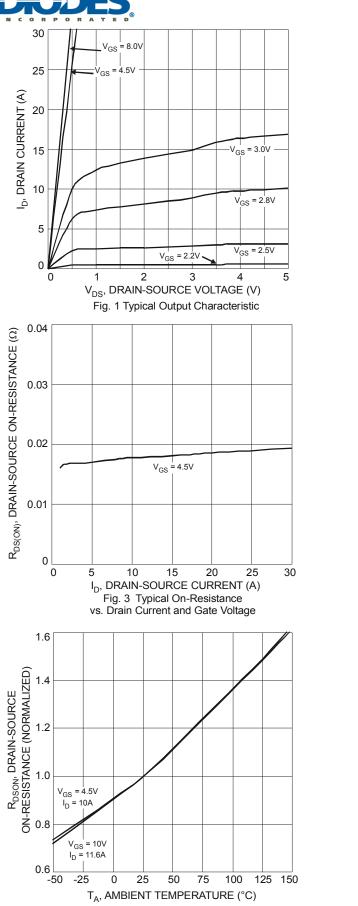
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>		_	1.0	μA	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>		_	±100	nA	$V_{GS}$ = ±20V, $V_{DS}$ = 0V	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.05	-	1.95	V	$V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A	
Static Drain-Source On-Resistance	Proven		11	14	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 11.6A	
	RDS (ON)	R <sub>DS (ON)</sub> —	15	20	11152	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 10A	
Forward Transfer Admittance	Y <sub>fs</sub>		8	_	S	V <sub>DS</sub> = 5V, I <sub>D</sub> = 11.6A	
Diode Forward Voltage	V <sub>SD</sub>		0.73	0.95	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss	_	867	—	pF	− V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V, − f = 1.0MHz	
Output Capacitance	Coss	_	85		pF		
Reverse Transfer Capacitance	C <sub>rss</sub>		81		pF		
Gate Resistance	R <sub>g</sub>		1.39	—	Ω	$V_{DS}$ = 0V, $V_{GS}$ = 0V, f = 1MHz	
Total Gate Charge	Qg		18.85	_	nC	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 15V, I <sub>D</sub> =11.6A	
Gate-Source Charge	Q <sub>gs</sub>		2.59	—	nC		
Gate-Drain Charge	Q <sub>gd</sub>		6.15	—	nC		
Turn-On Delay Time	t <sub>D(on)</sub>		5.46	_	ns	V <sub>DD</sub> = 15V, V <sub>GS</sub> = 10V, R <sub>L</sub> = 1.3Ω, R <sub>G</sub> = 3Ω, I <sub>D</sub> = 1A	
Turn-On Rise Time	tr		14.53		ns		
Turn-Off Delay Time	t <sub>D(off)</sub>		18.84	_	ns		
Turn-Off Fall Time	t <sub>f</sub>	_	6.01	_	ns		

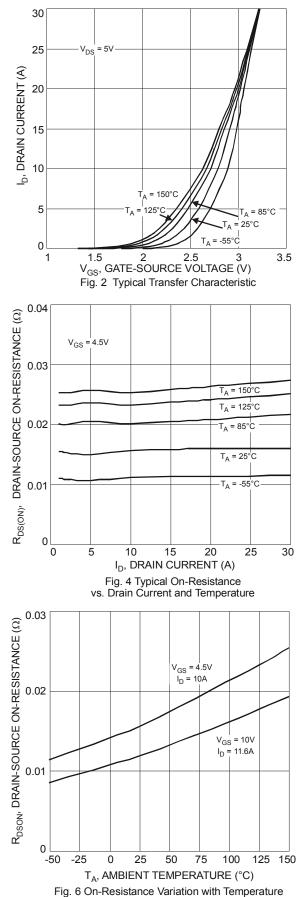
5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

6. Short duration pulse test used to minimize self-heating effect.
 7. Guaranteed by design. Not subject to product testing.

## DMN4468LSS

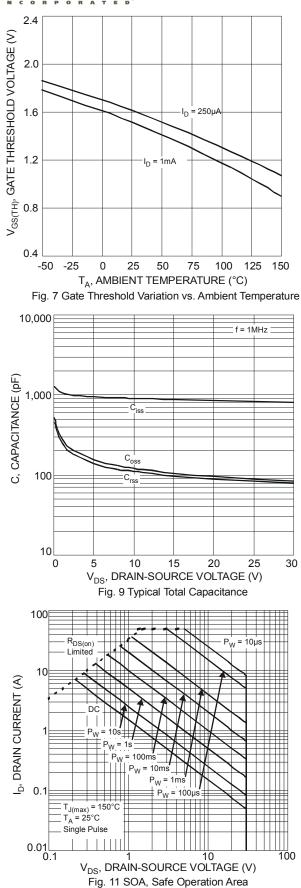






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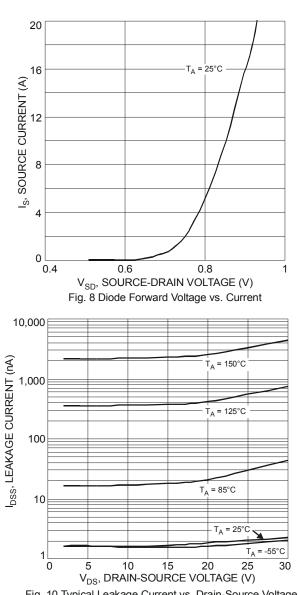
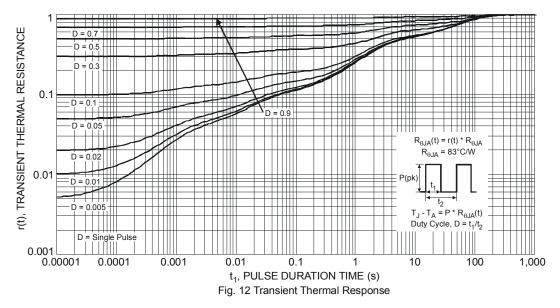


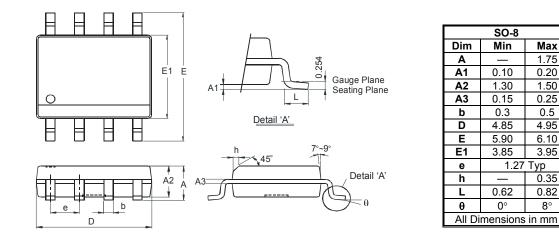
Fig. 10 Typical Leakage Current vs. Drain-Source Voltage





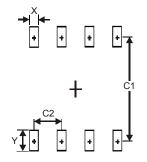
## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



## Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27



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